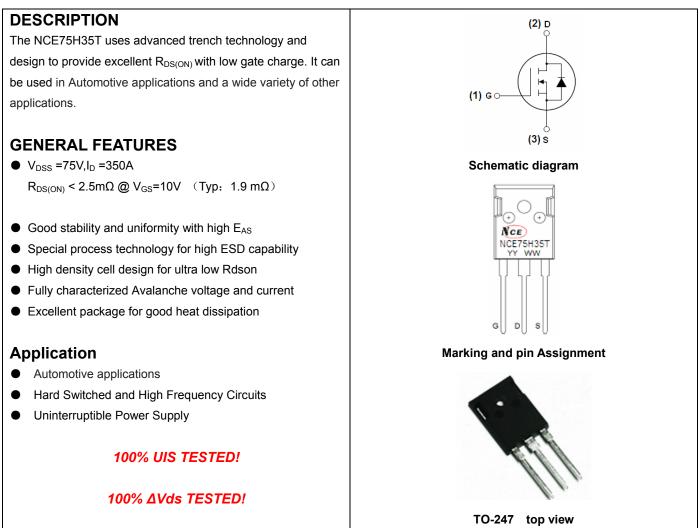




NCE N-Channel Enhancement Mode Power MOSFET



Package Marking And Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|-----------|----------------|-----------|------------|----------|
| NCE75H35T | NCE75H35T | TO-247 | - | - | - |

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit | |
|--|-----------------------|------------|------|--|
| Drain-Source Voltage | VDSS | 75 | V | |
| Gate-Source Voltage | Vgs | ±20 | V | |
| Drain Current-Continuous | Ι _D | 350 | Α | |
| Drain Current-Continuous(Tc=100℃) | I _D (100℃) | 270 | А | |
| Pulsed Drain Current | I _{DM} | 1280 | А | |
| Maximum Power Dissipation | PD | 460 | W | |
| Derating factor | | 3.07 | W/°C | |
| Single pulse avalanche energy (Note 3) | E _{AS} | 3500 | mJ | |
| Peak Diode Recovery dv/dt (Note 4) | dv/dt | 13 | V/ns | |
| Operating Junction and Storage Temperature Range | TJ,TSTG | -55 To 175 | °C | |





Thermal Characteristic

| Thermal Resistance, Junction-to-Case (Note 1) | R _{θJC} | 0.33 | °C /W |
|---|------------------|------|--------------|
|---|------------------|------|--------------|

Electrical Characteristics (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|---|-----|-------|------|--------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 75 | 86 | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =75V,V _{GS} =0V | | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | - | - | ±200 | nA |
| On Characteristics | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2 | 3 | 4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =40A | - | 1.9 | 2.5 | mΩ |
| Forward Transconductance | g fs | V _{DS} =25V,I _D =40A | 500 | - | - | S |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C _{lss} | | - | 19000 | - | PF |
| Output Capacitance | C _{oss} | V _{DS} =50V,V _{GS} =0V, F=1.0MHz | - | 1650 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | F=1.0MHZ | - | 770 | - | PF |
| Switching Characteristics | | | • | | | |
| Turn-on Delay Time | t _{d(on)} |)/ _20)// _40A | - | 43 | - | nS |
| Turn-on Rise Time | t _r | V _{DD} =38V,I _D =40A V _{GS} =10V,R _{GEN} =1.2Ω | - | 220 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | (Note2) | - | 170 | - | nS |
| Turn-Off Fall Time | t _f | (NOLEZ) | - | 260 | - | nS |
| Total Gate Charge | Qg | | - | 380 | 570 | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =38V,I _D =195A, | - | 75 | - | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V(Note2) | - | 105 | - | nC |
| Drain-Source Diode Characteristics | | | • | | | |
| Diode Forward Voltage | V _{SD} | V _{GS} =0V,I _S =40A | - | - | 1.2 | V |
| Reverse Recovery Time | t _{rr} | TJ = 25°C, IF = 40A | - | 130 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs(Note2) - 450 - | | - | nC | |
| Forward Turn-On Time | t _{on} | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) | | | | LS+LD) |

Notes:

1. Surface Mounted on FR4 Board, t ≤ 10 sec.

2. Pulse Test: Pulse Width \leq 400µs, Duty Cycle \leq 2%.

3. EAS condition: Tj=25 $^\circ C, V_{DD}$ =37.5V, V_G =10V, L=1mH, Rg=25 Ω



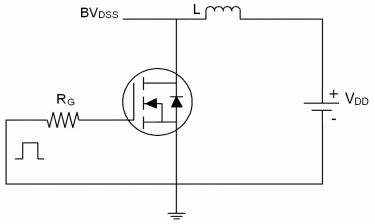
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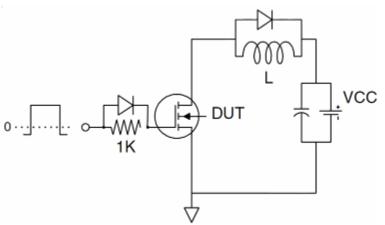


Test circuit

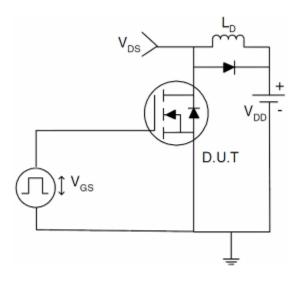
1) E_{AS} test Circuits



2) Gate charge test Circuit:



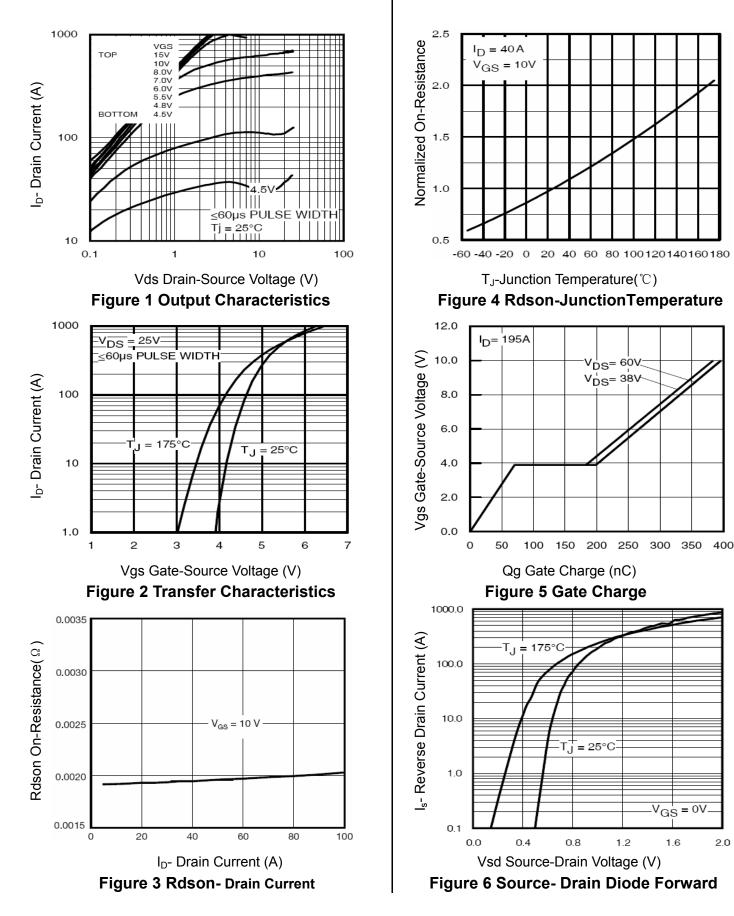
3) Switch Time Test Circuit:







TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



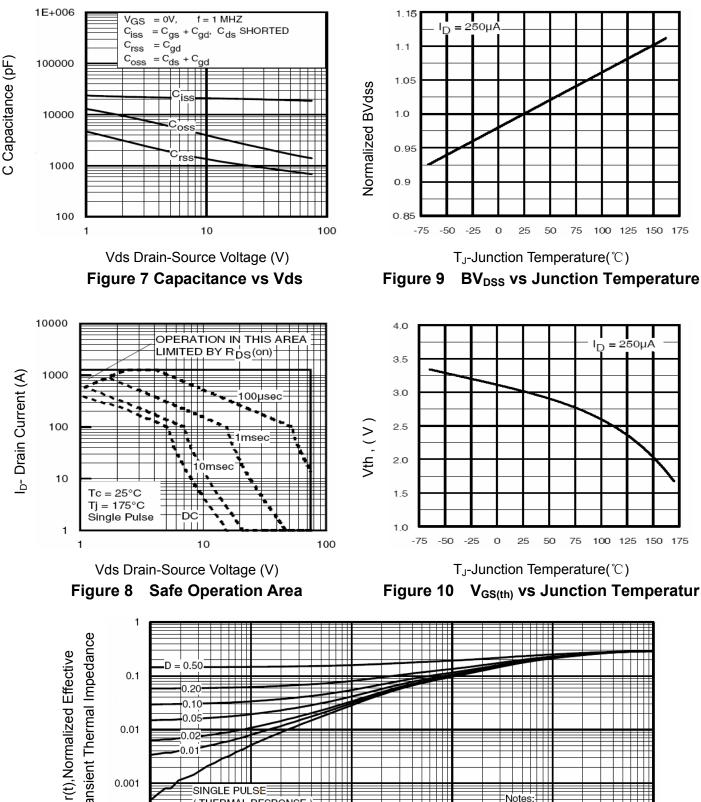
2.0

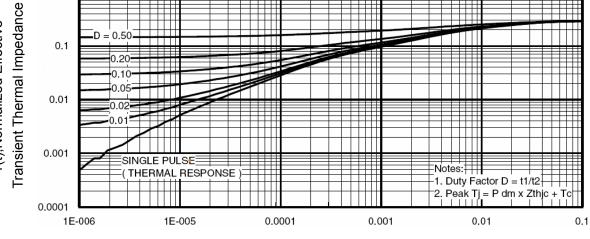


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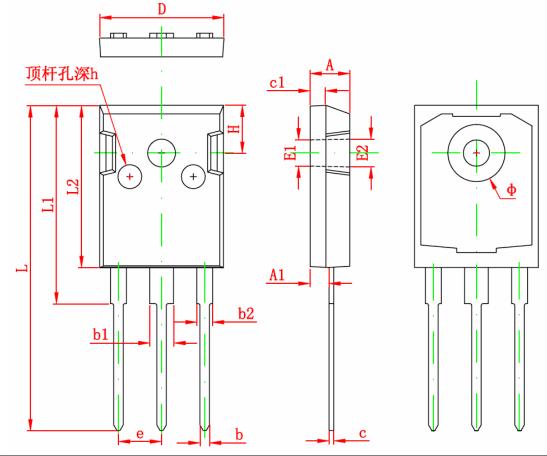
Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-247 PACKAGE INFORMATION



| Symbol | Dimensions I | n Millimeters | Dimensions In Inches | | |
|--------|--------------|---------------|----------------------|-------|--|
| Symbol | Min | Max | Min | Max | |
| Α | 4.850 | 5.150 | 0.191 | 0.200 | |
| A1 | 2.200 | 2.600 | 0.087 | 0.102 | |
| b | 1.000 | 1.400 | 0.039 | 0.055 | |
| b1 | 2.800 | 3.200 | 0.110 | 0.126 | |
| b2 | 1.800 | 2.200 | 0.071 | 0.087 | |
| c | 0.500 | 0.700 | 0.020 | 0.028 | |
| c1 | 1.900 | 2.100 | 0.075 | 0.083 | |
| D | 15.450 | 15.750 | 0.608 | 0.620 | |
| E1 | 3.500REF | | 0.138REF | | |
| E2 | 3.600REF | | 0.142REF | | |
| L | 40.900 | 41.300 | 1.610 | 1.626 | |
| L1 | 24.800 | 25.100 | 0.976 | 0.988 | |
| L2 | 20.300 | 20.600 | 0.799 | 0.811 | |
| Φ | 7.100 | 7.300 | 0.280 | 0.287 | |
| e | 5.450TYP | | 0.215TYP | | |
| Н | 5.980TYP | | 0.235 REF | | |
| h | 0.000 | 0.300 | 0.000 | 0.012 | |



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